Supporting information

Enhanced Magnetism and Anomalous Hall Transport through Two-dimensional Tungsten Disulfide Interfaces

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S1. Wet transfer process

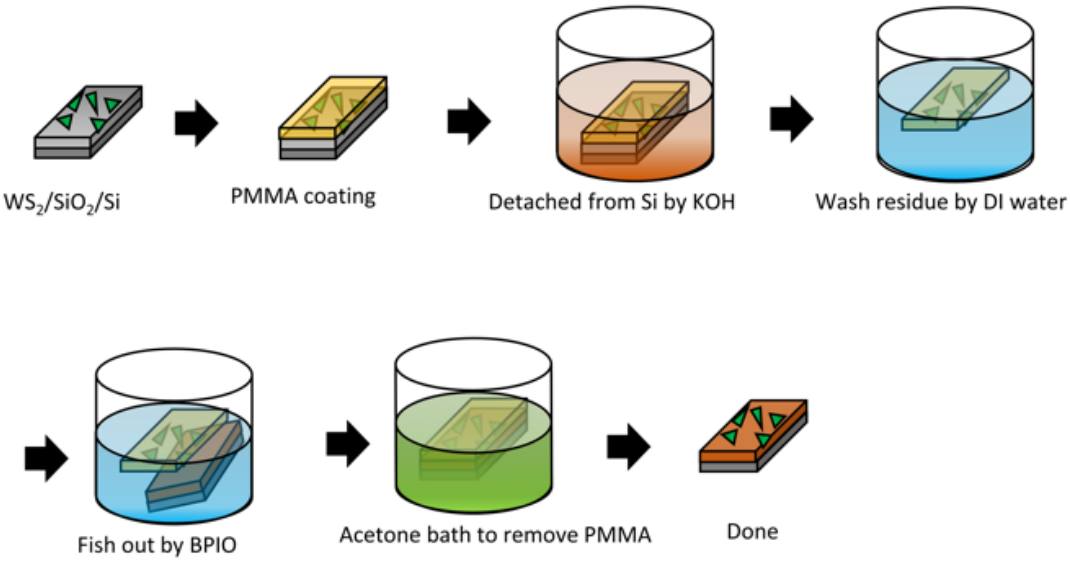

Figure S1. Schematic diagram of the wet transfer process.

S2. Pt/BPIO fitted by electron-electron interaction

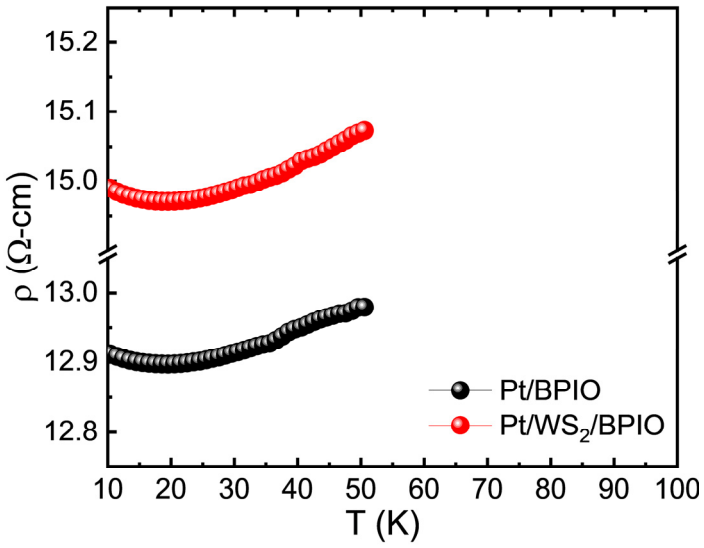

Figure S2. Low temperature resistivity behaviors for Pt/BPIO and Pt/WS_2/BPIO.

S3. Temperature-dependent resistance measurement of pure Pt

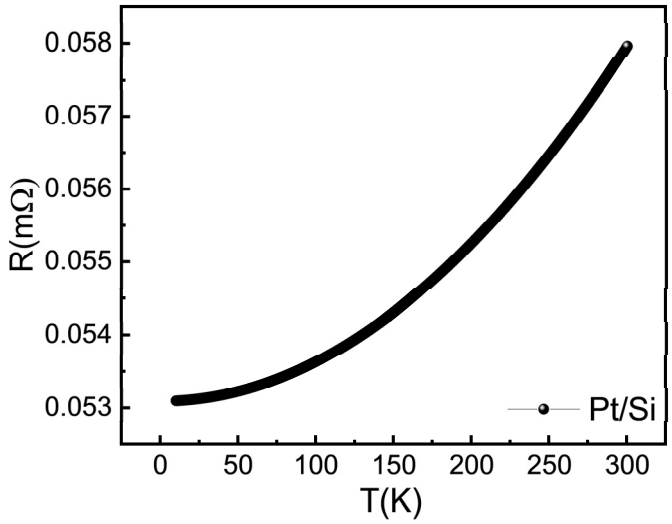

Figure S3. Temperature dependence of resistance of pure Pt